

Rectifier Diode



DS6000 - 1 March 2011 (LN28186)

FEATURES

- Double Side Cooling
- High Surge Capability

KEY PARAMETERS

V _{RRM}	2200V
I _{F(AV)}	2030A
IFSM	25700A

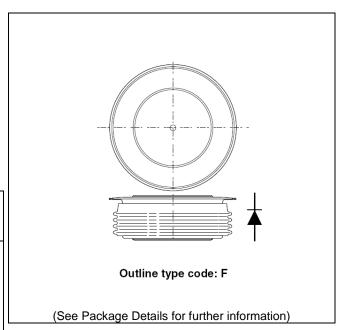


Fig. 1 Package outline

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{RRM} V	Conditions
DRD2030F22 DRD2030F20 DRD2030F18 DRD2030F16	2200 2000 1800 1600	V _{RSM} = V _{RRM} +100V

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DRD2030F22 for a 2200V device



CURRENT RATINGS

T_{case} = 75°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Sid	de Cooled			
I _{F(AV)}	Mean forward current	Half wave resistive load	2460	А
I _{F(RMS)}	RMS value	-	3860	А
١ _F	Continuous (direct) on-state current	-	3480	А

T_{case} = 100°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units		
Double Si	Double Side Cooled					
I _{F(AV)}	Mean forward current	Half wave resistive load	2030	А		
I _{F(RMS)}	RMS value	-	3190	А		
I _F	Continuous (direct) on-state current	-	2870	А		

SURGE RATINGS

Symbol	Parameter	Test Conditions		Units
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 175^{\circ}C$	25.7	kA
l ² t	I ² t for fusing	V _R = 0	3.30	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.02	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Double side cooled	DC	-	0.005	°C/W
T _{vj}	Virtual junction temperature	Blocking V _{DRM} / _{VRRM}		-40	175	°C
T _{stg}	Storage temperature range			-40	175	°C
F _m	Clamping force			18	26	kN

CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V _{FM}	Forward voltage	At 1500A peak, T _{case} = 25°C	-	1.20	V
I _{RM}	Peak reverse current	At V _{DRM} , T _{case} = 175°C	-	150	mA
Q _S Total stored charge	Total stored charge	I _F = 2000A, dI _{RR} /dt =10A/µs	-	4000	μC
QS	Total Stored Charge	$T_{case} = 175^{\circ}C, V_{R} = 100V$			
V _{TO}	Threshold voltage	At T _{vj} = 175°C	-	0.82	V
r _T	Slope resistance	At T _{vj} = 175°C	-	0.156	mΩ

G BYNEX

CURVES

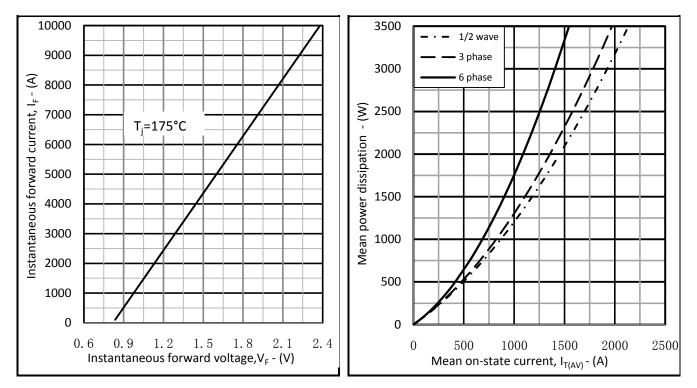
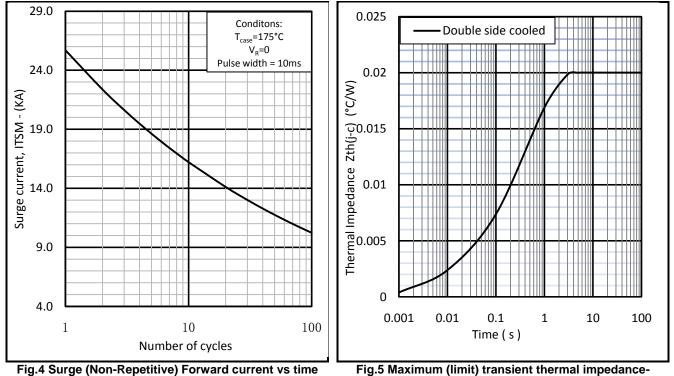


Fig.2 Maximum forward characteristics

Fig.3 Dissipation curves

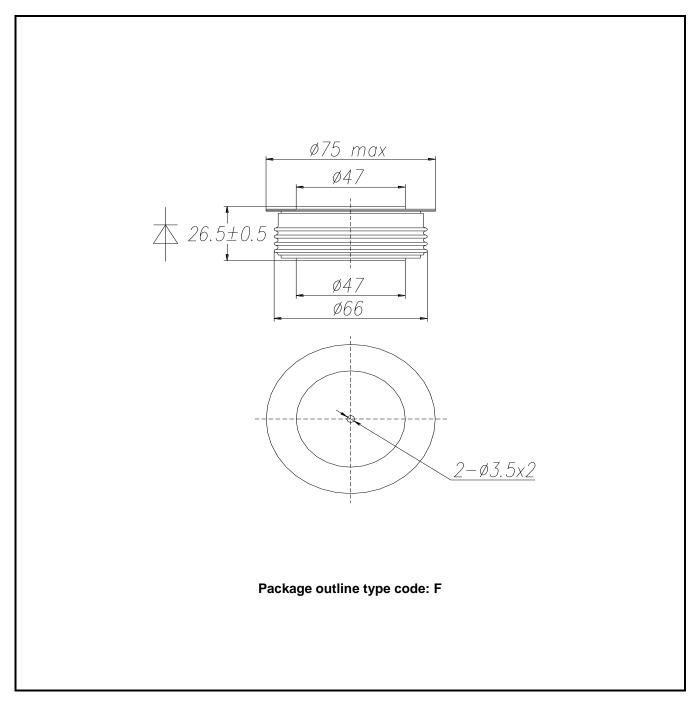


junction to case



PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note:

Some packages may be supplied with gate and or tags.



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